### **User Guide for the LTD-BK1000**

Product: LTE\_WCDMA Wireless Modem

Model name: LTD-BK1000

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### 1. Overview

The LTD-BK1000 is a personal mobile communication device that incorporates the latest compact radio technology, including smaller and lighter components and support for WCDMA(850/1900MHz) bands and LTE(700/850/1700/1900 MHz). This device acts as the vehicle's telematics system and connects to WCDMA (HSPA+) and LTE wireless networks and wireless modules to allow voice and data communication. Furthermore, this device can operate on land and water as well as other similar areas.

In LTE mode, the device provides uplink speeds of up to 50 Mbps and downlink speeds of up to 150 Mbps for seamless transfer of data such as movies and video calls. The device also supports the transfer of large amounts of data.

The device communicates with the host system via a standard RS-232 or USB port, and AT commands and control commands can be used to send data. Voice calls are also possible.

# 2. Major features

	Dimensions	34 x 40 x 3.5 mm (L x W x T) (Tolerance – width, length : TBD)	
	Weight	TBD g (max)	
Mechanical	Interface	USB, general purpose I/O pins	
	Temperature*	Operation: -20 ℃ - +70 ℃ Storage: -40 ℃ - +85 ℃	
	Main chipset	MDM9628	
	Memory	4Gb(NAND) / 1Gb(SDRAM)	
Technology	Standard	WCDMA (HSPA+) - DL Speed: 14.4 Mbps - UL Speed: 5.76 Mbps LTE - DL Speed: 150 Mbps - UL Speed: 50 Mbps	
	Band	WCDMA B2, B5 LTE B2, B4, B5, B17	
	Power	WCDMA: Typ. 24dBm (Power Class 3) LTE: Typ. 23dBm (Power Class 3)	
ETC	DC power	4 V	
ETC	Functions	Voice, data, SMS	



### 3.1 LGA Pad Layout (Top View)

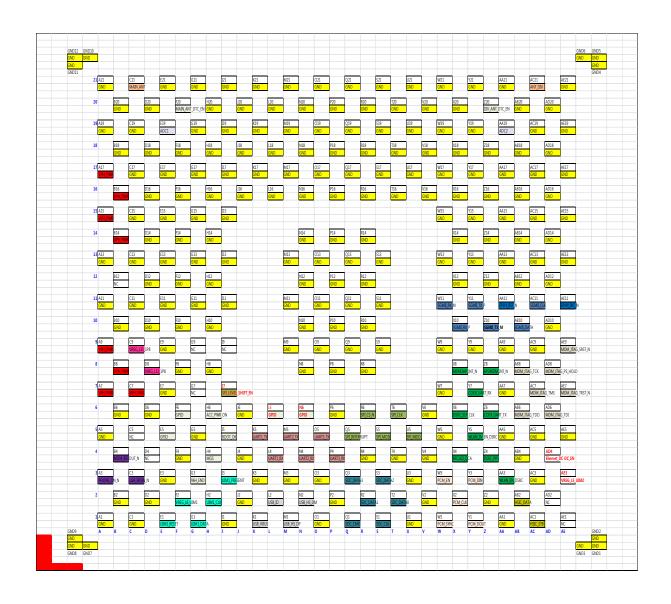


Figure 1. LGA Pin map



## 3.2 Pin description

PAD.	NAME	DIRECTION	DESCRIPTION	
Antenna	Interface Pads			
C21	MAIN_ANT	Input/Output	RF Main Antenna	
AC21	DIV_ANT	Input/Output	RF Diversity Antenna	
User Inte	erface Pads			
H6	ACC_PWR_ON	Input	ACC_PWR_ON	
15	BOOT_OK	Output	BOOT_OK	
H4	MSG	Output	MSG	
G3	96H_END	Output	96H_END	
F20	MAIN_ANT_DTC_EN	Output	Main ANT Detect Enable	
Z20	DIV_ANT_DTC_EN	Output	Diversity ANT Detect Enable	
17	SPI_LEVEL_SHIFT_EN	Output	SPI LEVEL SHIFT Enable	
AD4	ETHERNET_DCDC_ENABLE	Output	Ethernet power enable	
F6	GPIO1	Input/Output	General purpose I/O	
E5	GPIO2	(Do not use with External PU)	General purpose I/O	
L6	GPIO3	Input/Output (Not support INTERR	General purpose I/O	
N6	GPIO4	UPT)	General purpose I/O	
ADC Into	erface Pads	0.17		
E19	ADC1	Input	ADC Convertor input for main	
	ADOT	Прис	antenna detect	
AA19	ADC2	Input	ADC Convertor input for diversity	
DCM Int	l Dodo	·	antenna detect	
	erface Pads PCM_EN	Output	DCM 2.21 aval Shifter Enable	
W3 X2	PCM_CLK	Output Input	PCM 3.3 Level Shifter Enable PCM Clock	
W1	PCM_SYNC	Input	PCM Frame Sync	
Y3	PCM_DIN	Input	PCM Data In	
Y1	PCM_DOUT	Output	PCM Data Out	
	n Description	Cutput	T CIVI Data Out	
AC7	MDM_JTAG_TMS	Input/Output	JTAG mode select input	
AD8	MDM_STAG_TMS  MDM_JTAG_PS_HOLD	input	JTAG PS HOLD detect	
AD6	MDM_JTAG_TDI	Input	JTAG data input	
AE7	MDM_JTAG_TRST_N	Input	JTAG reset for debug	
AB6	MDM_JTAG_TDO	Output	JTAG debugging	
AB8	MDM_JTAG_TCK	Input	JTAG clock input	
AE9	MDM JTAG SRST N	Input	JTAG reset	
	erface Pads	. P		
N2	USB_HS_DM	Input/Output	USB high speed data (minus)	
	USB_HS_DP	Input/Output	USB high speed data (plus)	
K1	USB_VBUS	Input	USB power	
L2	USB_ID	Input	USB ID	
	erface Pads			
S1	SDC_CLK	Output	Secure digital controller clock	
Q1	SDC_CMD	Output	Secure digital controller command	
T2	SDC_DATA0	Input/Output	Secure digital controller data bit 0	
R2	SDC_DATA1	Input/Output	Secure digital controller data bit 1	
S3	SDC_DATA2	Input/Output	Secure digital controller data bit 2	

Table 1. Pin descriptions



Q3	SDC_DATA3	Input/Output	Secure digital controller data bit 3
	nterface Pads	h	
AA11	EPHY_RST_N or UIM2_RESET	Output	Ethernet PHY reset
AE11	EPHY_INT_N or UIM2_DETECT	Input	Ethernet PHY interrupt
AB10	SGMII_DATA or UIM2_CLK	Input/Output	SGMII input Output data
AD10	GND		Ground
X10	SGMII_RX_P	Input	SGMII receive - plus
W11	SGMII_RX_M	Input	SGMII receive -minus
Z10	SGMII_TX_M	Output	SGMII transmit - plus
Y11	SGMII_TX_P	Output	SGMII transmit -minus
AC11	SGMII_CLK or UIM2_DATA	Output	SGMII clock
SPI Inter	face Pads		
S5	SPI_MOSI	Output	SPI Serial Output
T6	SPI_CLK	Output	SPI Serial Clock
R6	SPI_CS_N	Output	SPI Chip Select
U5	SPI_MISO	Input	SPI Serial input
Q5	SPI_INTERRUPT	Input	MICOM → LGA SPI interrupt
UART In	terface Pads	•	•
M5	UART2_TX	Output	UART2 Transmit data
N4	UART2_RX	Input	UART2 Receive data
K5	UART1_TX	Output	Debug UART5 Transmit Data
L4	UART1_RX	Input	Debug UART5 Receive Data
O5	UART3_TX	Output	UART6 Transmit data
P4	UART3_RX	Input	UART6 Receive data
USIM Int	erface Pads	•	
13	UIM1_PRESENT	Input	Detection of an external UIM card
H2	UIM1_CLK	Output	Clock Output to an external UIM card
E1	UIM1_RESET	Output	Reset Output to an external UIM card
G1	UIM1_DATA	Input/Output	Data connection with an external UIM card
F2	VREG_L6_UIM1	Output	Supply Output for an external UIM card
E3	GND		Ground
D2	GND		Ground
A1	GND		Ground
C1	GND		Ground
B2	GND		Ground
HSIC Pir	Description		
AB2	HSIC_DATA	Input/Output	HSIC data
AC1	HSIC_STB	Input/Output	HSIC Strobe signal
AD2	NC		No Connect
AE1	NC		No Connect
DSRC P	in Description		
Y7	COEX_UART_RX	Input	LTE receiver sync for coexistence with UART
Z6	COEX_UART_TX	Output	LTE transmitter sync for coexistence with UART
X4	RFCLK2_QCA	Output	Low noise RF clock Output
AA3	WLAN_EN_DSRC	Output	WLAN Enable

Table 1. Pin descriptions



V6	DSRC_SLP_CLK	Output	DSPC sloop slock
X6 Y5	WLAN 3V_EN_DSRC	Output Output	DSRC sleep clock Used for WLAN enable
Z4	DSRC_PPS	Input/Output	Pulse Per Second
	MDM2AP_INT_N		
X8		Output	MDM to AP interrupt, PCM_LDO_EN
Z8 Control	AP2MDM_INT_N	Input	AP to MDM interrupt
Control		lanu.	ON/OFF Control
A3 B4	LGA_PHONE_ON MDM_RESOUT_N	Input	ON/OFF Control
	LGA RESIN N	Output	Reset Output
C3		Input	External Reset Input
	Supply Pads	Innut	nower aupply (4.0\/)
A17	VPH_PWR for PAM	Input	power supply (4.0V)
B16	VPH_PWR for PAM	Input	power supply (4.0V)
A15	VPH_PWR for PAM	Input	power supply (4.0V)
B14	VPH_PWR for PAM	Input	power supply (4.0V)
A9	VPH_PWR for PMIC	Input	power supply (4.0V)
B8	VPH_PWR for PMIC	Input	power supply (4.0V)
A7	VPH_PWR for PMIC	Input	power supply (4.0V)
C7	VPH_PWR for PMIC	Input	power supply (4.0V)
	Reference Pad	<u> </u>	1.50 (( 4.0)( ))
<u>C9</u>	VREG_L11_1P8	Output	LDO out for 1.8V pull up
D8	VREG_L11_1P8	Output	LDO out for 1.8V pull up
	Voltage Reference for SGMII		
AE3	(VREG_L5_UIM2) – Ethernet	Output	Ethernet I/O voltage
	IO전압 level		
NC Pad			In a
G9	NC		No Connect
B12	NC		No Connect
19	NC		No Connect
G7	NC		No Connect
C5	NC		No Connect
D4	NC		No Connect
<u> </u>	0.115		<u> </u>
A21	GND		Ground
E21	GND		Ground
G21	GND		Ground
121	GND		Ground
K21	GND		Ground
M21	GND		Ground
021	GND		Ground
Q21	GND		Ground
S21	GND		Ground
U21	GND		Ground
W21	GND		Ground
Y21	GND		Ground
AA21	GND		Ground
AE21	GND		Ground
B20	GND		Ground
	GND		Ground
D20			•
D20 H20 J20	GND GND		Ground Ground

Table 1. Pin descriptions



L20	GND	Cround	
N20	GND	Ground	
P20		Ground Ground	
R20	GND GND		
		Ground	
T20	GND	Ground	
V20	GND	Ground	
X20	GND	Ground	
AB20	GND	Ground	
AD20	GND	Ground	
A19	GND	Ground	
C19	GND	Ground	
G19	GND	Ground	
l19	GND	Ground	
K19	GND	Ground	
M19	GND	Ground	
019	GND	Ground	
Q19	GND	Ground	
S19	GND	Ground	
U19	GND	Ground	
W19	GND	Ground	
Y19	GND	Ground	
AC19	GND	Ground	
AE19	GND	Ground	
B18	GND	Ground	
D18	GND	Ground	
F18	GND	Ground	
H18	GND	Ground	
J18	GND	Ground	
L18	GND	Ground	
N18	GND	Ground	
P18	GND	Ground	
R18	GND	Ground	
T18	GND	Ground	
V18	GND	Ground	
X18	GND	Ground	
Z18	GND	Ground	
AB18	GND	Ground	
AD18	GND	Ground	
C17	GND	Ground	
E17	GND	Ground	
G17	GND	Ground	
117	GND	Ground	
K17	GND	Ground	
M17	GND	Ground	
017	GND	Ground	
Q17	GND	Ground	
S17	GND	Ground	
U17	GND	Ground	
W17	GND	Ground	
Y17	GND	Ground	

Table 1. Pin descriptions



ΛΛ17	CND	Cround
AA17	GND	Ground
AC17 AE17	GND	Ground
	GND	Ground
D16	GND	Ground
F16	GND	Ground
H16	GND	Ground
J16	GND	Ground
L16	GND	Ground
N16	GND	Ground
P16	GND	Ground
R16	GND	Ground
T16	GND	Ground
V16	GND	Ground
X16	GND	Ground
Z16	GND	Ground
AB16	GND	Ground
AD16	GND	Ground
C15	GND	Ground
E15	GND	Ground
G15	GND	Ground
l15	GND	Ground
W15	GND	Ground
Y15	GND	Ground
AA15	GND	Ground
AC15	GND	Ground
AE15	GND	Ground
D14	GND	Ground
F14	GND	Ground
H14	GND	Ground
X14	GND	Ground
Z14	GND	Ground
AB14	GND	Ground
AD14	GND	Ground
A13	GND	Ground
C13	GND	Ground
E13	GND	Ground
G13	GND	Ground
113	GND	Ground
W13	GND	Ground
Y13	GND	Ground
AA13	GND	Ground
AC13	GND	Ground
AE13	GND	Ground
D12	GND	Ground
F12	GND	Ground
H12	GND	Ground
X12	GND	Ground
Z12	GND	
AB12	GND	Ground
	GND	Ground Ground
AD12	עאוט	Giouna

Table 1. Pin descriptions



	LOND	
A11	GND	Ground
C11	GND	Ground
E11	GND	Ground
G11	GND	Ground
<u>  111</u>	GND	Ground
B10	GND	Ground
D10	GND	Ground
F10	GND	Ground
H10	GND	Ground
E9	GND	Ground
W9	GND	Ground
Y9	GND	Ground
AA9	GND	Ground
AC9	GND	Ground
F8	GND	Ground
H8	GND	Ground
E7	GND	Ground
W7	GND	Ground
AA7	GND	Ground
B6	GND	Ground
D6	GND	Ground
J6	GND	Ground
P6	GND	Ground
V6	GND	Ground
A5	GND	Ground
W5	GND	Ground
AA5	GND	Ground
AC5	GND	Ground
AE5	GND	Ground
F4	GND	Ground
J4	GND	Ground
R4	GND	Ground
T4	GND	Ground
V4	GND	Ground
AB4	GND	Ground
K3	GND	Ground
M3	GND	Ground
O3	GND	Ground
U3	GND	Ground
AC3	GND	Ground
J2	GND	Ground
P2	GND	Ground
V2	GND	Ground
Z2	GND	Ground
11	GND	Ground
01	GND	Ground
U1	GND	Ground
AA1	GND	Ground
GND1	GND	Ground
GND1	GND	Ground
GNDZ	ראוס ו	Gibuilu

Table 1. Pin descriptions

GND3	GND	Ground	
GND4	GND	Ground	
GND5	GND	Ground	
GND6	GND	Ground	
GND7	GND	Ground	
GND8	GND	Ground	
GND9	GND	Ground	
GND1	GND	Cround	
0	GND	Ground	
GND11	GND	Ground	
GND1	GND	Ground	
2		Ground	
N14	GND	Ground	
P14	GND	Ground	
R14	GND	Ground	
M13	GND	Ground	
013	GND	Ground	
Q13	GND	Ground	
S13	GND	Ground	
N12	GND	Ground	
P12	GND	Ground	
R12	GND	Ground	
M11	GND	Ground	
011	GND	Ground	
Q11	GND	Ground	
S11	GND	Ground	
N10	GND	Ground	
P10	GND	Ground	
R10	GND	Ground	
M9	GND	Ground	
O9	GND	Ground	
Q9	GND	Ground	
S9	GND	Ground	
N8	GND	Ground	
P8	GND	Ground	
R8	GND	Ground	
G5	GND	Ground	

Table 1. Pin descriptions

### 3.3 USB

This device supports universal serial bus (USB) connections for high-speed data communication. The relevant hardware satisfies the USB 2.0 specifications and supports maximum communications speeds of 480 Mbps

Pin NO.	Signal Name Pin I/O Function Descrip		Function Description
M1	USB_D+	Ю	USB Differential data line (+)
N2	USB_D-	IO	USB Differential data line (-)
K1	USB_VBUS	I	USB Power Supply

Table 2. USB Pin descriptions

### 3.4 Audio

This module includes a PCM interface. The pull-up and pull-down resistors attached to these pin must provide more than 50 Kohm of resistance.

Pin NO.	Signal Name	Pin I/O (Modem host)	Function Description
W1	PCM_SYNC	I	PCM Interface sync
X2	PCM_CLK	I	PCM Interface clock
Y1	PCM_TXD	0	PCM Interface digital audio data out
Y3	PCM_RXD	I	PCM Interface digital audio data in

Table 3. PCM Pin descriptions

### 3.5 User interface

Pin No.	Signal Name	Direction	Function
15	BOOT_OK	0	Indicates that the Modem boot is complete.
C3	RESET_IN	I	Control line to unconditionally restart the module.
H4	MSG	0	Indicates that the Modem receive Urgent message.
G3	96H_END	O Indicates that the 96hr sleep mode is end	
H6	ACC_ON_SLEEP	I	Control line to power on or 96hr sleep mode.
А3	Phone_ON	I	Control line to power on / off

Table 4. User interface Pin descriptions



## 4. Electrical specifications

### 4.1 Power supply specifications

The host system provides the power supply (V\_BATT)DC 4 V, 2.5 A to the device. The internal power supply module manages the power supplied to the integral circuits and maintains constant voltages. This module also controls each power block to minimize power consumption.

In particular, the PAM (power amplifier module) consumes a lot of power, so it receives a direct power supply of 4 V from the V\_BATT. Therefore the V\_BATT signal inputs only the supply power of the PAM, even when the absolute rating is higher. In addition, the entire power input module blocks and protects against high surges and ESD in the NAD module.

Pin No.	Signal Name	Direction	MIN	ТҮР	MAX
A7,C7,B8,A9, B14,A15,B16, A17	V_BATT	_	3.9 V	4 V	4.1 V

Table 5. Power supply specifications

# 4. Electrical specifications

## 4.2 Logic level specifications

## 4.2.1 Digital logic level specifications

Cianal Nama	Tuno	Lo	)W	Hi	gh	Lloit
Signal Name	Type	Min	Max	Min	Max	Unit
BOOT_OK	0	0	0.45	1.35	1.8	
RESET_IN		-0.3	0.63	1.17	1.8	
MSG	0	0	0.45	1.35	1.8	V
96H_END	0	0	0.45	1.35	1.8	
ACC_ON_SLEEP		0	0.63	1.17	1.8	

Table 6. Digital logic level specifications

### 5. RF specifications

#### 5.1 WCDMA

#### 5.1.1 Receiver

- .- Bandwidth: 5MHz
- .- Frequency: 869MHz 894MHz (B5), 1930MHz 1990MHz (B2)
- .- RF to Baseband Direct conversion (Zero IF)
- .- Modulation method: QPSK, 16QAM
- .- Sensitivity : ≤-104dBm (BER = Under 0.1%)

#### 5.1.2 Transmitter

- .- Frequency: 824MHz 849MHz (B5), 1850MHz 1910MHz (B2)
- .- Maximum RF Output: Power class3, 20.3dBm ~ 25.7dBm
- .- Modulation method: QPSK
- .- Baseband to RF Direct conversion (Zero IF)

#### 5.2 LTE

#### 5.2.1 Receiver

.- Bandwidth:

B2/B4(5 MHz, 10 MHz, 15 MHz, 20 MHz), B5/B17(5 MHz, 10 MHz)

.- Frequency:

B2 (1930 MHz – 1990 MHz), B4 (2110 MHz – 2155 MHz), B5 (869 MHz – 894 MHz), B17 (734 MHz – 746 MHz)

- .- RF to Baseband Direct conversion (Zero IF)
- .- Modulation method: QPSK, 16QAM and 64QAM
- .- Sensitivity:

B2 (≤-94.3dBm @QPSK, BW:10 MHz), B4 (≤-96.3dBm @QPSK, BW:10 MHz), B5 (≤-94.3dBm @QPSK, BW:10 MHz), B17 (≤-93.3dBm @QPSK, BW:10 MHz)



## 5. RF specifications

### 5.2.2 Transmitter

.- Frequency:

B2 (1850 MHz – 1910 MHz), B4 (1710 MHz – 1755 MHz), B5 (824 MHz – 849 MHz), B17 (704 MHz – 716MHz)

- .- Maximum RF Output : Power class3 , 20.3dBm ~ 25.7dBm
- .- Modulation method: QPSK and 16QAM
- .- Baseband to RF Direct conversion (Zero IF)



## 6. Mechanical specifications

### **6.1 Environment specifications**

```
.- Storage temp.: -40 ^{\circ}C - +85 ^{\circ}C
.- Operating temp.: -20 ^{\circ}C - +70 ^{\circ}C
 -30 ^{\circ}C - -20 ^{\circ}C, +70 ^{\circ}C - +80 ^{\circ}C : May cause performance degradation)
.- Operating humidity: 80% (60°C) relative humidity
```

# 6. Mechanical specifications

### 6.1 Mechanical dimensions

Dimensions	34 x 40.0 x 3.5 mm (L x W x T) (Tolerance – width, length : TBD)	
Weight	TBD grams(max.)	
Modem interface connector	12709HS-H40 (Manufacture vendor : YUNHO)	
Modem antenna Connector (Plug)	KR15005-DD , KR15005-DG (Manufacture vendor : KET)	

Table 7. Mechanical specification

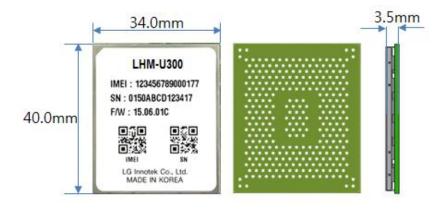


Figure 2. Mechanical dimension

## 7.1 WCDMA B5 electrical specifications

			_		Test Freq	CHANNEL			
	TE	ST ITEM	Spec.	Test Temperature	uency	4357	4400	4458	
1	Maximum	Output Power	20.3~25.7dBm	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
2		iency Error	-195 ~ +195Hz	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
3	Inner Loop Powe	er Control in the Uplin k	PASS	Normal	Mid	-	PASS	-	
4	Minimum	Output Power	-49dBm↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
5	Occupied E	Sandwidth (OBW)	5MHz ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
		SEM Band1 Offset2. 5-3.5MHz (at Freq+3. 5MHz)	-48.5dBc ↓			PASS	PASS	PASS	
6	Spectrum emis	SEM Band1 Offset3. 5-7.5MHz (at Freq+7. 5MHz)	-37.5dBc ↓	Normal	Low, Mid,	PASS	PASS	PASS	
, and the second	sion mask	SEM Band1 Offset7. 5-8.5MHz (at Freq+8. 5MHz)	-47.5dBc ↓	Nome	High	High	PASS	PASS	PASS
		SEM Band1 Offset8. 5-12.5MHz	-47.5dBc ↓			PASS	PASS	PASS	
7	Adjacent Chan nel Leakage Po	ACLR Offset +5/-5M Hz Rel	-32.2dBc ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
,	wer Ratio (ACL R)	ACLR Offset +10/-10 MHz Rel	-42.2dBc ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
8	Error Vector M agnitude(EVM)	EVM at Tx output po wer 24dBm /-18dBm	17.5% ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
9	Peak code do main error	PCDE at Tx output p ower 24dBm/-18dBm	-14dB ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
		Phase Discontinuity max EVM	17.5% ↓			-	PASS	-	
10	Phase Disconti nuity	Phase Discontinuity max Frequency Error	-195~195Hz	Normal	Mid	-	PASS	-	
	_	Phase Discontinuity max 1500Hz	36 degrees ↓			-	PASS	-	
11	Reference Sen sitivity Level	Ref Sense Go/No Go I^or=-104dBm/3.84M Hz	BER 0.1% ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
12	Maximum Inpu t Level	Max Input Go/No Go I^or=-25.7dBm/3.84M Hz	BER 0.1% ↓	Normal	Mid	-	PASS	-	

Table 8. WCDMA B5 RF specification



## 7.2 WCDMA B2 electrical specifications

			_		Test Freq	CHANNEL			
	TE	ST ITEM	Spec.	Test Temperature	uency	9662	9800	9938	
1	Maximum	Output Power	20.3~25.7dBm	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
2		iency Error	-195 ~ +195Hz	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
3	Inner Loop Powe	er Control in the Uplin k	PASS	Normal	Mid	-	PASS	-	
4	Minimum	Output Power	-49dBm ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
5	Occupied E	Sandwidth (OBW)	5MHz ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
		SEM Band1 Offset2. 5-3.5MHz (at Freq+3. 5MHz)	-48.5dBc ↓			PASS	PASS	PASS	
6	Spectrum emis	SEM Band1 Offset3. 5-7.5MHz (at Freq+7. 5MHz)	-37.5dBc ↓	Normal	Low, Mid,	PASS	PASS	PASS	
ŭ	sion mask	SEM Band1 Offset7. 5-8.5MHz (at Freq+8. 5MHz)	-47.5dBc ↓		High	High	PASS	PASS	PASS
		SEM Band1 Offset8. 5-12.5MHz	-47.5dBc ↓			PASS	PASS	PASS	
7	Adjacent Chan nel Leakage Po	ACLR Offset +5/-5M Hz Rel	-32.2dBc ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
,	wer Ratio (ACL R)	ACLR Offset +10/-10 MHz Rel	-42.2dBc ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
8	Error Vector M agnitude(EVM)	EVM at Tx output po wer 24dBm /-18dBm	17.5% ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
9	Peak code do main error	PCDE at Tx output p ower 24dBm/-18dBm	-14dB ↓	Normal	Low, Mid, High	PASS	PASS	PASS	
		Phase Discontinuity max EVM	17.5% ↓			-	PASS	ı	
10	Phase Disconti nuity	Phase Discontinuity max Frequency Error	-195~195Hz	Normal	Mid	-	PASS	-	
		Phase Discontinuity max 1500Hz	36 degrees ↓			-	PASS	-	
11	Reference Sen sitivity Level	Ref Sense Go/No Go I^or=-104dBm/3.84M Hz	BER 0.1% ↓	Normal, Temp L, Te mp H	Low, Mid, High	PASS	PASS	PASS	
12	Maximum Inpu t Level	Max Input Go/No Go I^or=-25.7dBm/3.84M Hz	BER 0.1% ↓	Normal	Mid	-	PASS	-	

Table 9. WCDMA B2 RF specification



## 7.3 LTE B2 electrical specifications

							TX Channe	l
	시형	넘 항목	Spec.	Test Temperature	Frequency	18650	18900	19150
1	Maximum Outp	ut Power(class 3)	20.3~25.7dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
2	Minimum C	Output Power	-39dBm ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
3	Freque	ncy Error	±0.1ppm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
4	Error Vector I	Magnitude(EVM)	12.5%↓(16QAM, 50RB)	Normal	Low, Mid, High	PASS	PASS	PASS
5	Relative Carrier Leakage Power	Carrier Leakage (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
6	In-band emission	In-band emission (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
7	EVM equalizer spectrum flatness	EVM equalizer spectrum flatness Range1	5.4 dB ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 1	-16.5 dBm ↓		Marie Marie	PASS	PASS	PASS
0	Spectrum emission	Spectrum Emission Mask upper/lower Area 2	-8.5 dBm ↓			PASS	PASS	PASS
8	mask	Spectrum Emission Mask upper/lower Area 3	-11.5 dBm ↓	Normal	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 4	-23.5 dBm ↓			PASS	PASS	PASS
		ACLR E-UTRA ±	-29.2dB↓			PASS	PASS	PASS
9	Adjacent Channel Leakage Power Ratio	ACLR UTRA Offset 1 ±	-32.2dB↓	Normal, Temp L, Temp H	H Low, Mid, High	PASS	PASS	PASS
		ACLR UTRA Offset 2 ±	-35.2dB↓			PASS	PASS	PASS
10	Reference Sensitivity Level @ 10MHz	Ref Sense throughput shall be ≥ 95%	-94.3 dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS

Table 10. LTE B2 RF specification

## 7.4 LTE B4 electrical specifications

							TX Channe	l
	시형	넘 항목	Spec.	Test Temperature	Frequency	20000	20175	20350
1	Maximum Outp	ut Power(class 3)	20.3~25.7dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
2	Minimum C	Output Power	-39dBm ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
3	Freque	ncy Error	±0.1ppm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
4	Error Vector I	Magnitude(EVM)	12.5%↓(16QAM, 50RB)	Normal	Low, Mid, High	PASS	PASS	PASS
5	Relative Carrier Leakage Power	Carrier Leakage (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
6	In-band emission	In-band emission (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
7	EVM equalizer spectrum flatness	EVM equalizer spectrum flatness Range1	5.4 dB ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 1	-16.5 dBm ↓		Low Middle h	PASS	PASS	PASS
8	Spectrum emission	Spectrum Emission Mask upper/lower Area 2	-8.5 dBm ↓			PASS	PASS	PASS
8	. mask	Spectrum Emission Mask upper/lower Area 3	-11.5 dBm ↓	Normal	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 4	-23.5 dBm ↓			PASS	PASS	PASS
		ACLR E-UTRA ±	-29.2dB↓			PASS	PASS	PASS
9	Adjacent Channel Leakage Power Ratio	ACLR UTRA Offset 1 ±	-32.2dB↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		ACLR UTRA Offset 2 ±	-35.2dB ↓			PASS	PASS	PASS
10	Reference Sensitivity Level @ 10MHz	Ref Sense throughput shall be ≥ 95%	-96.3 dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS

Table 11. LTE B4 RF specification

## 7.5 LTE B5 electrical specifications

							TX Channe	l
	시형	넘 항목	Spec.	Test Temperature	Frequency	20450	20525	20600
1	Maximum Outp	ut Power(class 3)	20.3~25.7dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
2	Minimum C	Output Power	-39dBm ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
3	Freque	ncy Error	±0.1ppm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
4	Error Vector I	Magnitude(EVM)	12.5%↓(16QAM, 50RB)	Normal	Low, Mid, High	PASS	PASS	PASS
5	Relative Carrier Leakage Power	Carrier Leakage (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
6	In-band emission	In-band emission (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
7	EVM equalizer spectrum flatness	EVM equalizer spectrum flatness Range1	5.4 dB ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 1	-16.5 dBm ↓		Malife	PASS	PASS	PASS
8	Spectrum emission	Spectrum Emission Mask upper/lower Area 2	-8.5 dBm ↓			PASS	PASS	PASS
8	. mask	Spectrum Emission Mask upper/lower Area 3	-11.5 dBm ↓	Normal	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 4	-23.5 dBm ↓			PASS	PASS	PASS
		ACLR E-UTRA ±	-29.2dB↓			PASS	PASS	PASS
9	Adjacent Channel Leakage Power Ratio	ACLR UTRA Offset 1 ±	-32.2dB ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		ACLR UTRA Offset 2 ±	-35.2dB ↓			PASS	PASS	PASS
10	Reference Sensitivity Level @ 10MHz	Ref Sense throughput shall be ≥ 95%	-94.3 dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS

Table 12. LTE B5 RF specification

## 7.17 LTE B17 electrical specifications

							TX Channe	l
	시형	넘 항목	Spec.	Test Temperature	Frequency	23780	23790	23800
1	Maximum Outp	ut Power(class 3)	20.3~25.7dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
2	Minimum C	Output Power	-39dBm ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
3	Freque	ncy Error	±0.1ppm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
4	Error Vector I	Magnitude(EVM)	12.5%↓(16QAM, 50RB)	Normal	Low, Mid, High	PASS	PASS	PASS
5	Relative Carrier Leakage Power	Carrier Leakage (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
6	In-band emission	In-band emission (3.2dBm $\pm$ 3.2dB)	-24.2 dBc	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
7	EVM equalizer spectrum flatness	EVM equalizer spectrum flatness Range1	5.4 dB ↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 1	-16.5 dBm↓		Marie Marie	PASS	PASS	PASS
	Spectrum emission	Spectrum Emission Mask upper/lower Area 2	-8.5 dBm ↓			PASS	PASS	PASS
8	mask	Spectrum Emission Mask upper/lower Area 3	-11.5 dBm↓	Normal	Low, Mid, High	PASS	PASS	PASS
		Spectrum Emission Mask upper/lower Area 4	-23.5 dBm↓			PASS	PASS	PASS
		ACLR E-UTRA ±	-29.2dB↓			PASS	PASS	PASS
9	Adjacent Channel Leakage Power Ratio	ACLR UTRA Offset 1 ±	-32.2dB↓	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS
		ACLR UTRA Offset 2 ±	-35.2dB↓			PASS	PASS	PASS
10	Reference Sensitivity Level @ 10MHz	Ref Sense throughput shall be ≥ 95%	-93.3 dBm	Normal, Temp L, Temp H	Low, Mid, High	PASS	PASS	PASS

Table 13. LTE B17 RF specification

### 8. RFx information

The strength of the RF field produced by the wireless module or modules embedded in the TCU is well within all international RF exposure limits known at this time. Because the wireless modules embedded in the TCU emit less than the maximum amount of energy permitted in radio frequency safety standards and recommendations, the manufacturer believes these modules are safe for use.

Regardless of the power levels, care should be taken to minimize human contact during normal operation. This module should be remain more than 20 cm (8 inches) from the body when wireless devices are on and transmitting.

This transmitter must not be collocated or operated in conjunction with any other antenna or transmitter. Operation is subject to the following two conditions: (1) this module does not cause interference, (2) this module accepts any interference that may cause undesired operation.

### 8.1 Information for the integrator

The integrator must not provide information to the end user regarding how to install or remove this RF module in the user manual of the end product. The user manual that is provided by the integrator for end users must include the following information in a prominent location. To comply with FCC RF exposure requirements, the antenna used for this transmitter must be installed to provide a separation distance of at least 20 cm from all persons and must not be collocated or operated in conjunction with any other antenna or transmitter. The label for the end product must include FCC ID: YZP-BK1000 or A RF transmitter inside, IC ID: 7414C-BK1000

### 9. Approbation FCC

This module complies with FCC/IC rules.

FCC: Part 22, Part 24, Part 27

IC: RSS-130, RSS-132, RSS-133, RSS-139

Furthermore, this device complies with FCC/IC radiation exposure limits set forth for uncontrolled environments.

This module must be installed and operated with minimum distance of 20 cm between the radiating element and the user.

This module must not be co-located with any other transmitters or antennas

Cet module est conforme à l'exposition de FCC et IC rayonnements limites é-tablies pour un environnement non contrôlé. Cet module doit être installé et utilisé avec une distance minimale de 20 cm entre le radiateur et votre corps. Ce module ne doit pas être même endroit avec d'autres émetteur ou antennes.

To comply with FCC/IC regulations limiting both the maximum RF output power and human exposure to RF radiation, the maximum antenna gain including cable loss in a mobile-only exposure condition must not exceed the values listed in the following table.

Band	Frequency Range [MHz]	Maximum Antenna Gain[dBi]
WCDMA(B5)	826.40~846.6	4.5
WCDMA(B2)	1852.4~1907.6	2.0
LTE(B2)	1850~1910	2.0
LTE(B4)	1710~1755	2.0
LTE(B5)	824~849	4.5
LTE(B17)	704~716	4.5

To satisfy the FCC's exterior labeling requirements, the following text must appear on the exterior of the end product.

Contains transmitter module FCC ID: YZP-BK1000 Contains transmitter module IC ID: 7414C-BK1000

Changes or modifications to this equipment may cause harmful interference unless the modifications are expressly approved in the instruction manual. Users may lose the authority to operate this equipment if an unauthorized change or codification is made.

Note: If this module is intended for use in a portable device, additional testing will be required to satisfy the RF exposure and SAR requirements of FCC Part 2.1093 and RSS-102.

